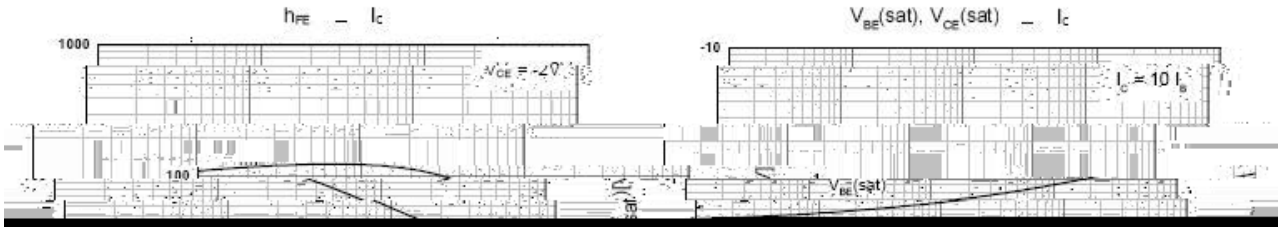
TO-252 PNP Silicon PNP transistor in a TO-252 Plastic Package.

Low Speed ,Load Formed for Surface Mount Application.

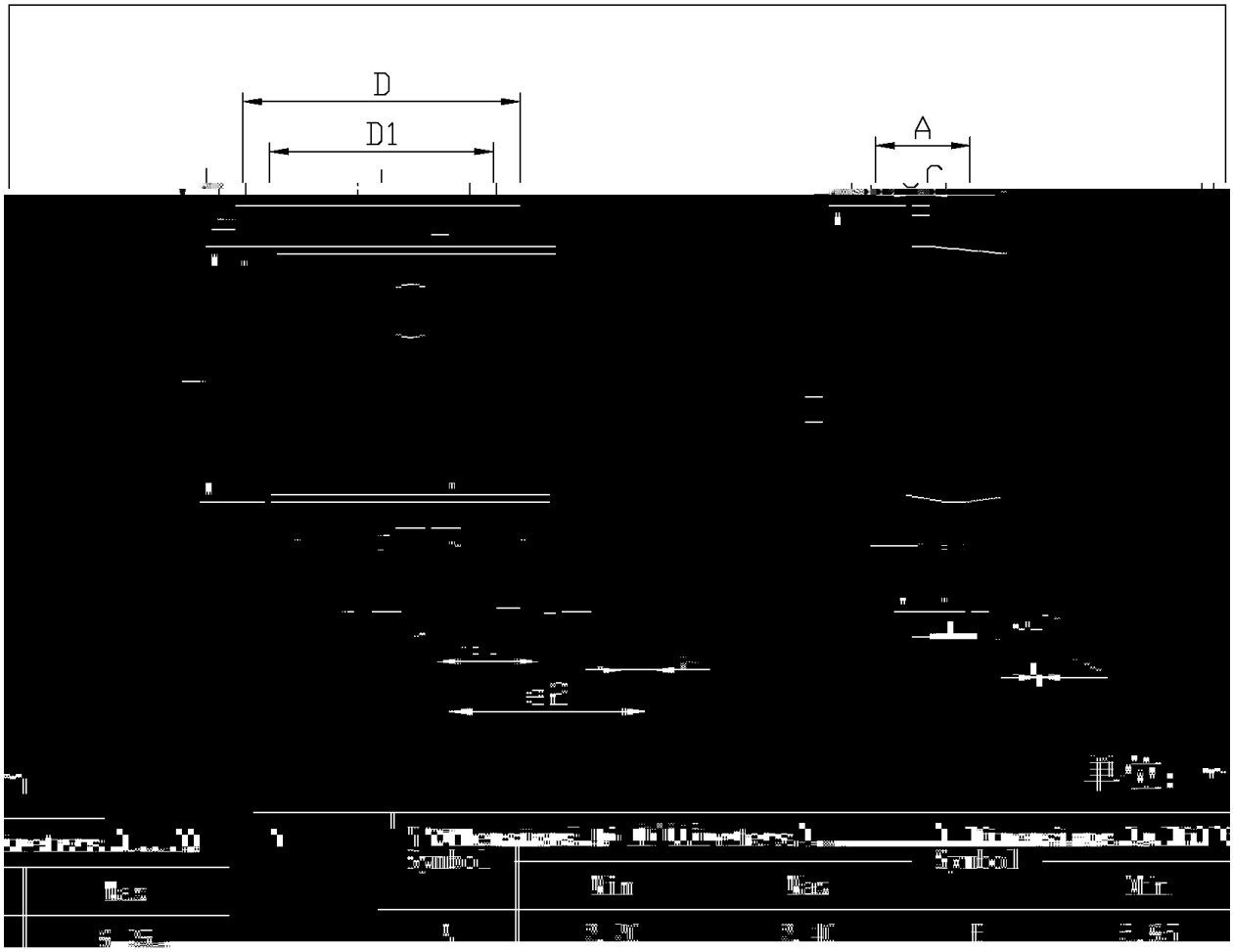
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-100	V
Collector to Emitter Voltage	V_{CEO}	-100	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-3.0	A
Collector Current – Continuous(Pulse)	I_{CP}	-5.0	A
Base Current - Continuous	I_B	-1.0	A
Collector Power Dissipation	$P_C(T_C$=25)	15	W
Collector Power Dissipation	P		

C

/ Electrical Characteristic Curve



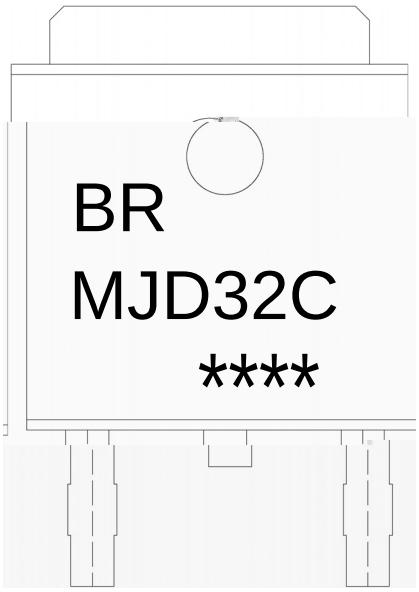
/ Package Dimensions



	0.90				
.00	0.10	D1	5.10	5.50	K

TO-252

/ Marking Instructions



BR

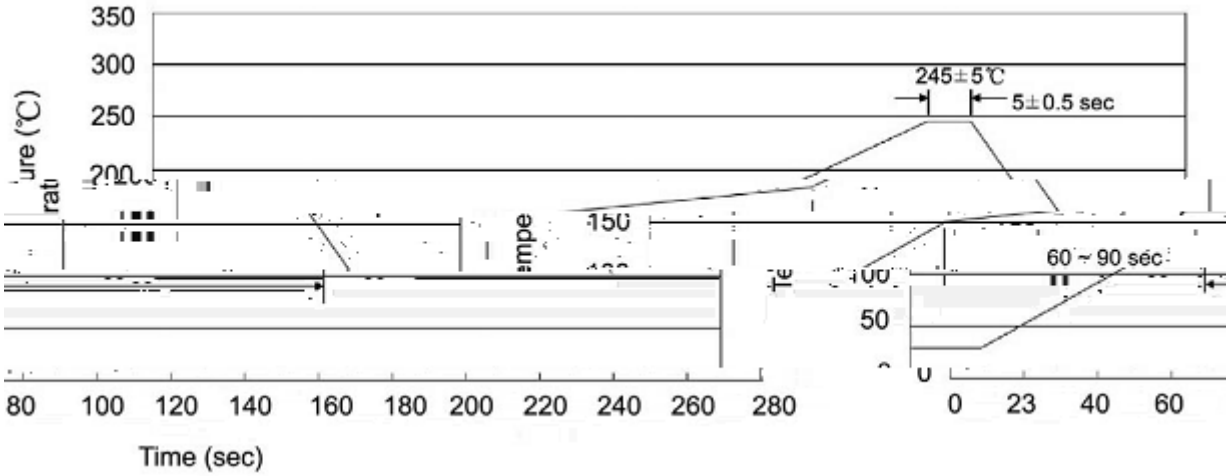
MJD32C

****

Note:

BR:	Company Code
MJD32C:	Product Type.
****:	Lot No. Code, code change with Lot No.

( ) / Temperature Profile for IR Reflow Soldering(Pb-Free)



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